

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/5496790/publications.pdf Version: 2024-02-01



LIE SUM

#	Article	IF	CITATIONS
1	Graphene Conductance Uniformity Mapping. Nano Letters, 2012, 12, 5074-5081.	4.5	152
2	Synthesis Methods of Two-Dimensional MoS2: A Brief Review. Crystals, 2017, 7, 198.	1.0	138
3	Unveiling the charge transfer dynamics steered by built-in electric fields in BiOBr photocatalysts. Nature Communications, 2022, 13, 2230.	5.8	117
4	Frame assisted H2O electrolysis induced H2 bubbling transfer of large area graphene grown by chemical vapor deposition on Cu. Applied Physics Letters, 2013, 102, .	1.5	109
5	Large-area uniform graphene-like thin films grown by chemical vapor deposition directly on silicon nitride. Applied Physics Letters, 2011, 98, .	1.5	81
6	Vertically Aligned Graphene Coating is Bactericidal and Prevents the Formation of Bacterial Biofilms. Advanced Materials Interfaces, 2018, 5, 1701331.	1.9	72
7	Catalyst-Free, Selective Growth of ZnO Nanowires on SiO ₂ by Chemical Vapor Deposition for Transfer-Free Fabrication of UV Photodetectors. ACS Applied Materials & Interfaces, 2015, 7, 20264-20271.	4.0	69
8	Noncatalytic chemical vapor deposition of graphene on high-temperature substrates for transparent electrodes. Applied Physics Letters, 2012, 100, .	1.5	66
9	Controllable chemical vapor deposition of large area uniform nanocrystalline graphene directly on silicon dioxide. Journal of Applied Physics, 2012, 111, .	1.1	59
10	Low Partial Pressure Chemical Vapor Deposition of Graphene on Copper. IEEE Nanotechnology Magazine, 2012, 11, 255-260.	1.1	57
11	Electrical Properties of Self-Assembled Branched InAs Nanowire Junctions. Nano Letters, 2008, 8, 1100-1104.	4.5	56
12	Growth mechanism of graphene on platinum: Surface catalysis and carbon segregation. Applied Physics Letters, 2014, 104, .	1.5	56
13	Graphene GaN-Based Schottky Ultraviolet Detectors. IEEE Transactions on Electron Devices, 2015, 62, 2802-2808.	1.6	50
14	Influence of graphene synthesizing techniques on the photocatalytic performance of graphene–TiO ₂ nanocomposites. Physical Chemistry Chemical Physics, 2013, 15, 15528-15537.	1.3	43
15	Quantum Hall effect in graphene decorated with disordered multilayer patches. Applied Physics Letters, 2013, 103, .	1.5	39
16	Ultrahigh Surfaceâ€Enhanced Raman Scattering of Graphene from Au/Graphene/Au Sandwiched Structures with Subnanometer Gap. Advanced Optical Materials, 2016, 4, 2021-2027.	3.6	38
17	New Strategy for Black Phosphorus Crystal Growth through Ternary Clathrate. Crystal Growth and Design, 2017, 17, 6579-6585.	1.4	38
18	Extremely low density InAs quantum dots realized in situ on (100) GaAs. Nanotechnology, 2004, 15, 1763-1766.	1.3	35

#	Article	IF	CITATIONS
19	A Mechanism for Highly Efficient Electrochemical Bubbling Delamination of CVDâ€Grown Graphene from Metal Substrates. Advanced Materials Interfaces, 2016, 3, 1500492.	1.9	33
20	Frequency mixing and phase detection functionalities of three-terminal ballistic junctions. Nanotechnology, 2007, 18, 195205.	1.3	30
21	Memristive and Memcapacitive Characteristics of a Au/Ti– \$hbox{HfO}_{2}\$-InP/InGaAs Diode. IEEE Electron Device Letters, 2011, 32, 131-133.	2.2	30
22	Asymmetric Quantum-Dot Pixelation for Color-Converted White Balance. ACS Photonics, 2021, 8, 2158-2165.	3.2	30
23	Perovskite Quantum Dots for Emerging Displays: Recent Progress and Perspectives. Nanomaterials, 2022, 12, 2243.	1.9	30
24	A Novel SR Latch Device Realized by Integration of Three-Terminal Ballistic Junctions in InGaAs/InP. IEEE Electron Device Letters, 2008, 29, 540-542.	2.2	29
25	Pore-free bubbling delamination of chemical vapor deposited graphene from copper foils. Journal of Materials Chemistry C, 2015, 3, 8634-8641.	2.7	29
26	Two-In-One Method for Graphene Transfer: Simplified Fabrication Process for Organic Light-Emitting Diodes. ACS Applied Materials & Interfaces, 2018, 10, 7289-7295.	4.0	29
27	Direct Chemical Vapor Deposition of Large-Area Carbon Thin Films on Gallium Nitride for Transparent Electrodes: A First Attempt. IEEE Transactions on Semiconductor Manufacturing, 2012, 25, 494-501.	1.4	23
28	Graphene bolometer with thermoelectric readout and capacitive coupling to an antenna. Applied Physics Letters, 2018, 112, .	1.5	23
29	High-responsivity photodetectors made of graphene nanowalls grown on Si. Applied Physics Letters, 2019, 115, .	1.5	23
30	Chiral charge pumping in graphene deposited on a magnetic insulator. Physical Review B, 2017, 95, .	1.1	22
31	Transfer-free, lithography-free and fast growth of patterned CVD graphene directly on insulators by using sacrificial metal catalyst. Nanotechnology, 2018, 29, 365301.	1.3	22
32	Insights into the Mechanism for Vertical Graphene Growth by Plasma-Enhanced Chemical Vapor Deposition. ACS Applied Materials & Interfaces, 2022, 14, 7152-7160.	4.0	20
33	Gate-defined quantum-dot devices realized in InGaAs/InP by incorporating a HfO2 layer as gate dielectric. Applied Physics Letters, 2009, 94, 042114.	1.5	18
34	Electrochemical Bubbling Transfer of Graphene Using a Polymer Support with Encapsulated Air Gap as Permeation Stopping Layer. Journal of Nanomaterials, 2016, 2016, 1-7.	1.5	18
35	Rapid chemical vapor deposition of graphene on liquid copper. Synthetic Metals, 2016, 216, 93-97.	2.1	18
36	Encapsulation of graphene in Parylene. Applied Physics Letters, 2017, 110, .	1.5	18

#	Article	IF	CITATIONS
37	Process Optimization of Passive Matrix GaN-Based Micro-LED Arrays for Display Applications. Journal of Electronic Materials, 2019, 48, 5195-5201.	1.0	18
38	Monolithic Integrated Device of GaN Micro-LED with Graphene Transparent Electrode and Graphene Active-Matrix Driving Transistor. Materials, 2019, 12, 428.	1.3	17
39	In Situ Growth of CVD Graphene Directly on Dielectric Surface toward Application. ACS Applied Electronic Materials, 2020, 2, 238-246.	2.0	17
40	Nonlinear electrical properties of Si three-terminal junction devices. Applied Physics Letters, 2010, 97, .	1.5	16
41	Graphene p–n–p junctions controlled by local gates made of naturally oxidized thin aluminium films. Carbon, 2012, 50, 1987-1992.	5.4	16
42	Quantum-dot array with a random rough interface encapsulated by atomic layer deposition. Optics Letters, 2022, 47, 166.	1.7	16
43	GaN nanorod light emitting diodes with suspended graphene transparent electrodes grown by rapid chemical vapor deposition. Applied Physics Letters, 2013, 103, 222105.	1.5	14
44	Transfer-free, lithography-free, and micrometer-precision patterning of CVD graphene on SiO2 toward all-carbon electronics. APL Materials, 2018, 6, 026802.	2.2	14
45	Unusual thermopower of inhomogeneous graphene grown by chemical vapor deposition. Applied Physics Letters, 2014, 104, 021902.	1.5	13
46	Direct growth of high quality graphene nanowalls on dielectric surfaces by plasma-enhanced chemical vapor deposition for photo detection. Optical Materials Express, 2020, 10, 2909.	1.6	13
47	Chemical liquid phase deposition of thin aluminum oxide films. Chinese Journal of Chemistry, 2004, 22, 661-667.	2.6	12
48	Large-Scale Proton-Implant-Defined VCSEL Arrays With Narrow Beamwidth. IEEE Electron Device Letters, 2018, 39, 390-393.	2.2	11
49	Dependence of Beam Quality on Optical Intensity Asymmetry in In-Phase Coherently Coupled VCSEL Array. IEEE Journal of Quantum Electronics, 2018, 54, 1-6.	1.0	10
50	Tripling Light Conversion Efficiency of μLED Displays by Light Recycling Black Matrix. IEEE Photonics Journal, 2022, 14, 1-7.	1.0	10
51	Gate-defined double quantum dot with integrated charge sensors realized in InGaAs/InP by incorporating a high-I [®] dielectric. Applied Physics Letters, 2010, 96, .	1.5	9
52	ZnO nanorods/graphene/Ni/Au hybrid structures as transparent conductive layer in GaN LED for low work voltage and high light extraction. Solid-State Electronics, 2016, 126, 5-9.	0.8	9
53	The Growth of Graphene on Ni–Cu Alloy Thin Films at a Low Temperature and Its Carbon Diffusion Mechanism. Nanomaterials, 2019, 9, 1633.	1.9	9
54	Ultra-compact electrically controlled beam steering chip based on coherently coupled VCSEL array directly integrated with optical phased array. Optics Express, 2019, 27, 13910.	1.7	9

#	Article	IF	CITATIONS
55	Metal-Catalyst-Free Growth of Patterned Graphene on SiO ₂ Substrates by Annealing Plasma-Induced Cross-Linked Parylene for Optoelectronic Device Applications. ACS Applied Materials & Interfaces, 2019, 11, 14427-14436.	4.0	8
56	Quantum Dot Color Conversion Efficiency Enhancement in Micro-Light-Emitting Diodes by Non-Radiative Energy Transfer. IEEE Electron Device Letters, 2021, 42, 1184-1187.	2.2	8
57	Role of surface microstructure and shape on light extraction efficiency enhancement of GaN micro-LEDs: A numerical simulation study. Displays, 2022, 73, 102172.	2.0	8
58	Silica and Alumina Thin Films Grown by Liquid Phase Deposition. Materials Science Forum, 2005, 475-479, 1725-1728.	0.3	7
59	Mechanism of Electrochemical Delamination of Two-Dimensional Materials from Their Native Substrates by Bubbling. Sensors, 2015, 15, 31811-31820.	2.1	7
60	Transfer-Free Graphene-Like Thin Films on GaN LED Epiwafers Grown by PECVD Using an Ultrathin Pt Catalyst for Transparent Electrode Applications. Materials, 2019, 12, 3533.	1.3	7
61	Reliability of High-Voltage GaN-Based Light-Emitting Diodes. IEEE Transactions on Device and Materials Reliability, 2019, 19, 402-408.	1.5	7
62	Chemical vapor deposition of graphene on refractory metals: The attempt of growth at much higher temperature. Synthetic Metals, 2019, 247, 233-239.	2.1	7
63	Analysis of optical coupling behavior in two-dimensional implant-defined coherently coupled vertical-cavity surface-emitting laser arrays. Photonics Research, 2018, 6, 1048.	3.4	7
64	Facile growth of aluminum oxide thin film by chemical liquid deposition and its application in devices. Nanotechnology Reviews, 2020, 9, 876-885.	2.6	7
65	Hybrid Device of Blue GaN Light-Emitting Diodes and Organic Light-Emitting Diodes with Color Tunability for Smart Lighting Sources. ACS Omega, 2022, 7, 5502-5509.	1.6	7
66	Changing planar thin film growth into self-assembled island formation by adjusting experimental conditions. Thin Solid Films, 2005, 476, 68-72.	0.8	6
67	A sequential logic device realized by integration of in-plane gate transistors in InGaAsâ^•InP. Applied Physics Letters, 2008, 92, 012116.	1.5	6
68	Transport properties of three-terminal ballistic junctions realized by focused ion beam enhanced etching in InGaAs/InP. Applied Physics Letters, 2008, 93, 133110.	1.5	5
69	Multiple growth of graphene from a pre-dissolved carbon source. Nanotechnology, 2020, 31, 345601.	1.3	5
70	Research on the reliability of Micro LED high-density solder joints under thermal cycling conditions. Journal of Physics: Conference Series, 2022, 2221, 012010.	0.3	5
71	Electron Resonant Tunneling Through InAsâ^•GaAs Quantum Dots Embedded in a Schottky Diode with an AlAs Insertion Layer. Journal of the Electrochemical Society, 2006, 153, G703.	1.3	4
72	Room-Temperature Observation of Electron Resonant Tunneling Through InAsâ^•AlAs Quantum Dots. Electrochemical and Solid-State Letters, 2006, 9, G167.	2.2	4

#	Article	IF	CITATIONS
73	Thermoelectric effects in graphene at high bias current and under microwave irradiation. Scientific Reports, 2017, 7, 15542.	1.6	4
74	<title>Self-organized LPE growth of
Al<formula><inf><roman>0.3</roman></inf></formula>Ga<formula><inf><roman>0.7</roman></inf></formula
microtips for integrated SNOM sensors</title> . , 2002, , .	>As	3
75	High responsivity sensing of unfocused laser and white light using graphene photodetectors grown by chemical vapor deposition. Optical Materials Express, 2016, 6, 2158.	1.6	3
76	Aspiration-assisted fabrication of patterned quantum dot films for photo-emissive color conversion. Journal of Materials Science, 2021, 56, 1504-1514.	1.7	3
77	GaN LEDs with <i>in situ</i> synthesized transparent graphene heat-spreading electrodes fabricated by PECVD and penetration etching. Journal of Materials Chemistry C, 2022, 10, 6794-6804.	2.7	3
78	Metal-Free Graphene as Transparent Electrode for GaN-Based Light-Emitters. Japanese Journal of Applied Physics, 2013, 52, 08JG05.	0.8	2
79	High Light Extraction Efficiency AlGaInP LEDs With Proton Implanted Current Blocking Layer. IEEE Electron Device Letters, 2016, 37, 1303-1306.	2.2	2
80	Morphology regulation of TiO2 thin film by ALD growth temperature and its applications to encapsulation and light extraction. Journal of Materials Science: Materials in Electronics, 2020, 31, 21316-21324.	1.1	2
81	Graphene-assisted preparation of large-scale single-crystal Ag(111) nanoparticle arrays for surface-enhanced Raman scattering. Nanotechnology, 2021, 32, 025301.	1.3	2
82	SCANNING ELECTRON MICROSCOPY OBSERVATION OF IN-DEVICE InAs/AlAs QUANTUM DOTS BY SELECTIVE ETCHING OF CAPPING LAYERS. Modern Physics Letters B, 2007, 21, 859-866.	1.0	1
83	Comment on "Mechanism of non-metal catalytic growth of graphene on silicon―[Appl. Phys. Lett. 100, 231604 (2012)]. Applied Physics Letters, 2012, 101, 096101.	1.5	1
84	Chemical vapor deposition of nanocrystalline graphene directly on arbitrary high-temperature insulating substrates. , 2012, , .		1
85	A Hybridâ€Type CVD System for Graphene Growth. Chemical Vapor Deposition, 2015, 21, 176-180.	1.4	1
86	Graphene Transfer: A Mechanism for Highly Efficient Electrochemical Bubbling Delamination of CVD-Grown Graphene from Metal Substrates (Adv. Mater. Interfaces 8/2016). Advanced Materials Interfaces, 2016, 3, .	1.9	1
87	High Quality Graphene Thin Films Synthesized by Glow Discharge Method in A Chemical Vapor Deposition System Using Solid Carbon Source. Materials, 2020, 13, 2026.	1.3	1
88	Dynamic phase manipulation of vertical-cavity surface-emitting lasers via on-chip integration of microfluidic channels. Optics Express, 2021, 29, 1481.	1.7	1
89	Graphene coated magnetic nanoparticles facilitate the release of biofuels and oleochemicals from yeast cell factories. Scientific Reports, 2021, 11, 20612.	1.6	1
90	Micro-fabricated Al/sub 0.3/Ga/sub 0.7/As pyramids for potential SPM applications. , 2004, , .		0

#	Article	IF	CITATIONS
91	Gate-defined quantum devices realized on an InGaAs/InP heterostructure by incorporating a high-κ dielectric material. , 2009, , .		0
92	Metallization Reliability of GaN-Based High-Voltage Light-Emitting Diodes. IEEE Transactions on Device and Materials Reliability, 2021, 21, 472-478.	1.5	0
93	Direct Growth of Transparent Graphene Electrodes on GaN LEDs Using Metal Proximity Catalytic Effect. , 2021, , .		0
94	Direct Growth of Large-area Graphene by Cross-linked Parylene Graphitization toward Photodetection. , 2019, , .		0
95	Direct Patterned Growth of PECVD Graphene Transparent Electrodes on GaN LED Epiwafers Using Co as a Sacrificial Catalyst Layer. , 2020, , .		0